NSN 5961-01-077-2367

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-077-2367 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.056 inches and 0.075 inches **End Application:** Deep submergence systems programs (dssp); support equipment, mx peacekeeper missile, kidd class ddg; arleigh burke class ddg; oliver perry class ffg; spruance class dd (963); austin ship class lpd-4 amphibious transport docks; ticonderoga class cg (47); nimitz class cvn; forrestal class cv **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage, peak total value and 75.0 regulator voltage **Current Rating Per Characteristic:** 0.50 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Weapon system essential; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No